

Application No. 10/643,682
Response to Office Action

Customer No. 01933

Amendments to the Claims:

This listing of claims will replace all prior versions, and listing of claims in the application.

Listing of Claims:

Claim 1. (Currently Amended) A chemical treatment method by which a metal film formed on a material to be subjected to film formation is etched into a predetermined pattern, comprising:

(a) a cathode electrolysis reduction step [[of]] comprising performing electrolysis reduction ~~for the on a~~ metal film as a cathode by using one of [[a]] first (i) an acidic reduction treatment solution containing an acid radical and (ii) an alkaline reduction treatment solution containing a halogen ion; and

(b) an etching acid dip step [[of]] dipping comprising ~~etching~~ the metal film ~~into a second acidic~~ in an etching treatment solution after the cathode electrolysis reduction step.

Claim 2. (Currently Amended) A method according to claim 1, wherein the first cathode electrolysis reduction step is carried out with the acidic reduction treatment solution [[is]] which comprises one member compound selected from the group consisting

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of hydrochloric acid, sulfuric acid, carboxylic acid, hydrogen fluoride[[,]] and phosphoric acid.

Claim 3. (Currently Amended) A method according to claim 1, wherein the cathode electrolysis reduction step is carried out with the alkaline reduction treatment solution which comprises a halogen ion is ~~one member~~ selected from the group consisting of sodium chloride, potassium chloride[[,]] and potassium iodide.

Claim 4. (Currently Amended) A method according to claim 1, wherein the ~~second acidic etching~~ treatment solution contains a halogen ion.

Claim 5. (Currently amended) A chemical treatment method by which a metal film formed on a material to be subjected to film formation is etched into a predetermined pattern, comprising:

(a) a cathode electrolysis reduction step [[of]] comprising performing electrolysis reduction ~~for the~~ on a metal film as a cathode by using a reduction treatment solution containing a halogen ion; and

(b) an acid dip step [[of]] comprising dipping the metal film into an acidic etching treatment solution after the cathode electrolysis reduction step.

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Claim 6. (Currently Amended) A method according to claim 5, wherein the acidic etching treatment solution contains a halogen ion.

Claim 7. (Currently amended) A method according to any one of claims 4 to claim 6, wherein the halogen ion in the acidic etching treatment solution is a chloride ion.

Claim 8. (Currently amended) A method according to any one of claims 1 to 6, wherein the cathode electrolysis reduction step further comprises dipping a portion of the metal film into [[a]] an etching treatment solution containing a halogen ion.

Claim 9. (Currently Amended) A method according to claim 8, wherein [[a]] metal forming the metal film is formed from one metal selected from the group consisting of chromium, titanium, tungsten, palladium[[,]] and molybdenum.

Claim 10. (Currently Amended) A method according to claim 8, wherein [[a]] metal forming the metal film is formed from an alloy containing at least one metal selected from the group consisting of chromium, titanium, tungsten, palladium[[,]] and molybdenum.

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Claim 11. (Currently Amended) A chemical treatment method by which a metal film formed on a material to be subjected to film formation is etched into a predetermined pattern[[,]] comprising:

~~wherein the dipping a metal film is dipped in an acidic treatment solution containing a halogen ion, and performing electrolysis reduction is performed for on the metal film as a cathode.~~

Claim 12. (Currently Amended) A method according to any one of claims 1 to 5 ~~and or~~ 11, wherein [[a]] metal forming the metal film is formed from one metal selected from the group consisting of chromium, titanium, tungsten, palladium[[,]] and molybdenum.

Claim 13. (Currently Amended) A method according to any one of claims 1 to 5 ~~and or~~ 11, wherein [[a]] metal forming the metal film is formed from an alloy containing at least one element selected from the group consisting of chromium, titanium, tungsten, palladium[[,]] and molybdenum.

Claim 14. (Original) A method according to claim 11, wherein the halogen ion is a chloride ion.

Claims 15 to 23 (Canceled).

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Claim 24. (New) A method according to claim 4, wherein the halogen ion in the etching treatment solution is a chloride ion.

Claim 25. (New) A method according to claim 5, wherein the halogen ion in the reduction treatment solution is a chloride ion.

Claim 26. (New) A method according to claim 3, wherein the halogen ion is potassium chloride.

Claim 27. (New) A method according to claim 1, wherein the metal film comprises a nickel chrome alloy.

Claim 28. (New) A method according to claim 5, wherein the metal film comprises a nickel chrome alloy.

Claim 29. (New) A method according to claim 11, wherein the metal film comprises a nickel chrome alloy.